

# 2SB1688

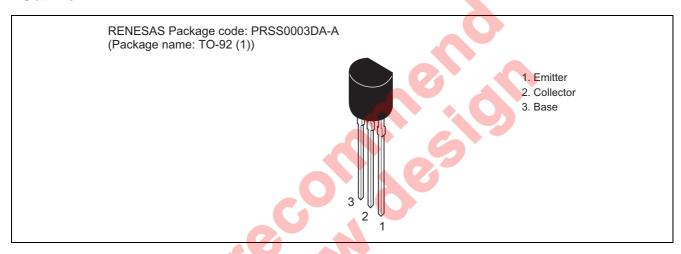
Silicon PNP Epitaxial High voltage amplifier

REJ03G0679-0300 (Previous ADE-208-975A) Rev.3.00 Aug.10.2005

#### **Features**

• High breakdown voltage  $V_{CEO} = -300V \text{ min}$ 

#### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit	
Collector to base voltage	$V_{CBO}$	-300	V	
Collector to emitter voltage	$V_{CEO}$	-300	V	
Emitter to base voltage	$V_{EBO}$	<b>-</b> 5	V	
Collector current	I <sub>C</sub>	-50	mA	
Collector power dissipation	P <sub>C</sub>	750	mW	
Junction temperature	T <sub>j</sub>	150	°C	
Storage temperature	T <sub>stg</sub>	-55 to +150	°C	

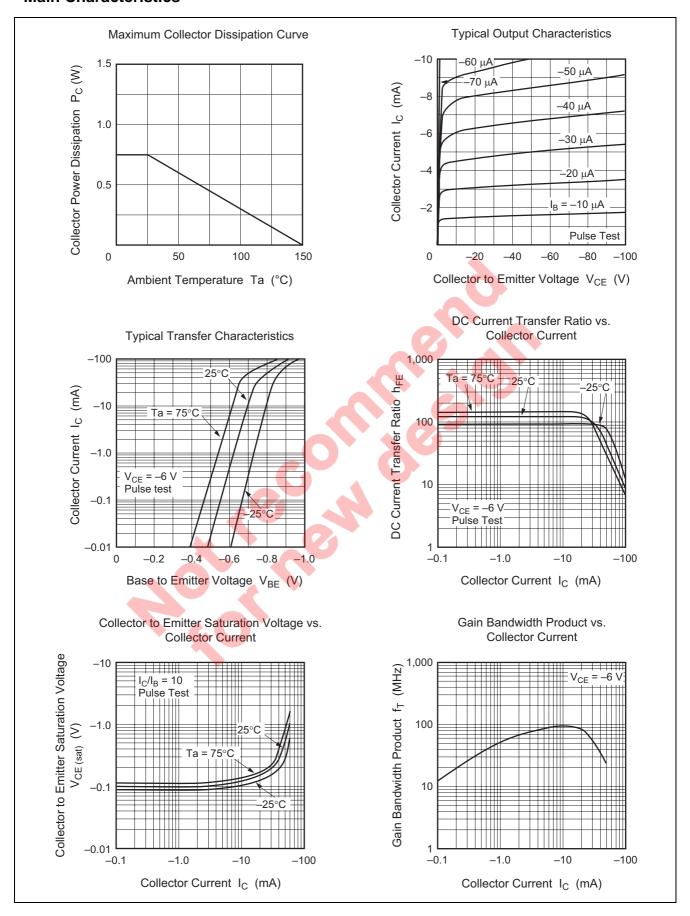
### **Electrical Characteristics**

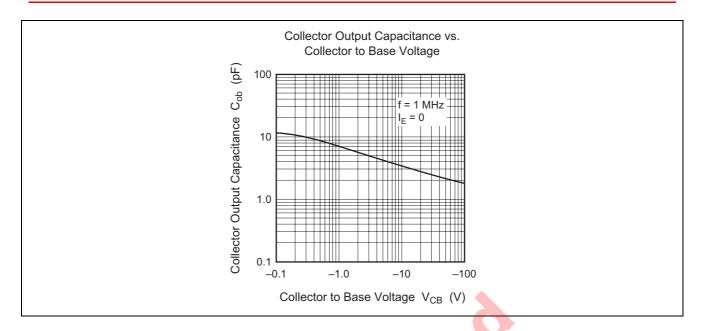
 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Collector cutoff current	I <sub>CBO</sub>	_	_	-0.1	μΑ	$V_{CB} = -300V, I_{E} = 0$
	I <sub>CEO</sub>	_	_	-0.1	μΑ	$V_{CE} = -300V$ , $R_{BE} = \infty$
Emitter cutoff current	I <sub>EBO</sub>	_	_	-10	μΑ	$V_{EB} = -5 \text{ V}, I_{C} = 0$
Base to emitter voltage	$V_{BE}$	_	_	-0.75	V	$V_{CE} = -6V, I_{C} = -1mA$
DC current transfer ratio	h <sub>FE</sub>	80	_	160	_	$V_{CE} = -6V, I_{C} = -2mA$
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	_	-0.9	V	$I_{C} = -30 \text{mA}, I_{B} = -3 \text{mA}$

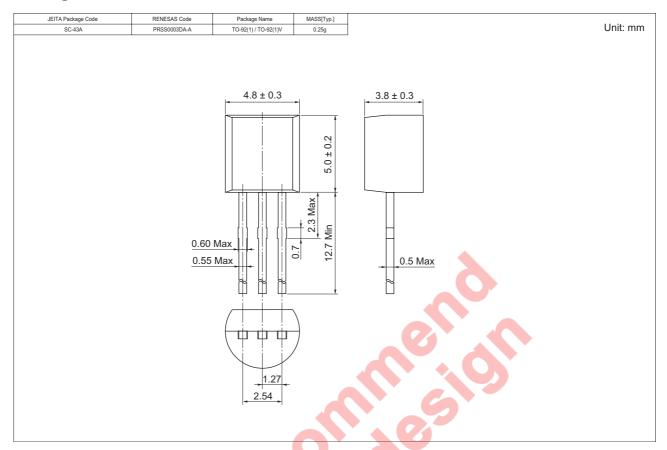


#### **Main Characteristics**





## **Package Dimensions**



## **Ordering Information**

Part Name	Quantity		Shipping Container
2SB1688TZ-E	2500	Hol	d Box, Radial Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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